



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#8/A  
B6B  
213C8

In re application of:

Yeong-Kwan KIM, et al.

Serial No. 09/902,607

Filed: July 12, 2001

For: Semiconductor Device Having  
Thin Film Formed by Atomic  
Layer Deposition and Method  
for Fabricating the Same

Examiner: Toniae M. Thomas

Art Unit: 2822

Atty. Docket No.: 249/258

TECHNOLOGY CENTER 2800

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FEB 11 2003

AMENDMENT UNDER 37 C.F.R. § 1.111

Commissioner for Patents  
United States Patent and Trademark Office  
Washington, D.C. 20231

Sir:

In response to the Office Action mailed on October 07, 2002, kindly amend the subject application as follows:

IN THE SPECIFICATION:

Kindly amend the specification as follows: